Hall Ticket Number :						R-19	
Codo: 10AE22T						R-19	
Code: 19A522T							

I B.Tech. II Semester Supplementary Examinations July/August 2022

Programming through Python

(Common to EEE & ECE)

Max. Marks: 70 Time: 3 Hours

Answer any five full questions by choosing one question from each unit (5x14 = 70 Marks)

			Marks	СО	Blooms Level
		UNIT-I			
1.	a)	Describe and illustrate Boolean operators with examples.	7M	CO1	L2
	b)	Write a program using if statements in Python.	7M	CO1	L3
		OR			
2.		Difference between sequential, selection, and iterative control	14M	CO1	L4
		UNIT-II			
3.		Define set and illustrate set in Python with suitable example	14M	CO2	L2
0.		OR	17171	002	
4.		Define dictionary data type in python? Illustrate dictionary with suitable			
		example.	14M	CO2	L3
		UNIT-III			
5.	a)	Write a python program to write some text into a file.	7M	CO3	L2
	b)	Discuss about string traversal in python	7M	CO3	L2
		OR			
6.	a)	How to deal with text files in python?	7M	CO3	L3
	b)	Write a python program to read the lines of a file.	7M	CO3	L3
-		UNIT-IV	4 4 1 4	004	1.0
7.		Illustrate encapsulation with suitable example.	14IVI	CO4	L3
0	۵)	OR Explain the difference between a reference and dereferenced value	7M	CO4	L3
Ο.	a) b)	Explain the difference between a reference and dereferenced value Infer about constructors in Python	7 IVI 7M	CO4	L3 L4
	D)	inter about constructors in Fython	/ IVI	004	L 4
		UNIT-V			
9.		What is stack? Demonstrate stack operations with the example.	14M	CO5	L3
		OR			
10.		Outline the concept of queue implementation using python list.	14M	CO5	L4

Hall Ticket Number :			
	R-1	9	
Code: 19AC21T I B.Tech. II Semester Supplementary Examinations July/Aug Differential Equations and Vector Calculus (Common to All Branches)	ust 202	2	_
Max. Marks: 70 Answer any five full questions by choosing one question from each unit (5x	Time: 3 14 = 70 <i>h</i>		
UNIT-I	Marks	СО	Blooms Level
Solve $\frac{d^2y}{dx^2} + y = e^{-x} + e^x \sin x$ OR	14M	CO1	L3
Solve $(D^2 + 1)x = t \cos t$ given $x = 0, \frac{dx}{dt} = 0$ at $t = 0$.	14 M	CO1	L3
Solve $x^2 \frac{d^2 y}{dx^2} - 4x \frac{dy}{dx} + 6y = x^2$	14M	CO2	L3
Solve $(2x+3)^2 \frac{d^2y}{dx^2} - (2x+3)\frac{dy}{dx} - 12y = 6x$	14M	CO2	L3
Solve $x^2(y-z)p + y^2(z-x)q = z^2(x-y)$ OR	14M	CO3	L3
Using the method of separation of variables, solve $\frac{\partial u}{\partial x} = 2 \frac{\partial u}{\partial t} + u \text{ where } u(x,0) = 6e^{-3x}$	14M	CO3	L3
	,		
formed by the lines $x = \pm 1$ and $y = \pm 1$.	14M	CO4	L2
Find the angle between the surfaces $x^2 + y^2 + z^2 = 9$ and $z = x^2 + y^2 - 3$ at the point (2,-1,2)	14M	CO4	L2
formed by the planes x=0, x=a, y=0,y=b, z=0,z=c. OR	14M	CO5	L3
Verify Green's theorem in the plane for $\int (3x^2 - 8y^2) dx + (4y - 6xy) dy$ where	;		

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C is the region bounded by x = 0, y = 0 and x + y = 1.

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L3

14M CO5

Hall Ticket Number :						

Code: 19A421T

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I B.Tech. II Semester Supplementary Examinations July/August 2022

Electronic Devices and Circuits

(Common to EEE & ECE)

Max. Marks: 70 Time: 3 Hours Answer any five full questions by choosing one question from each unit (5x14 = 70 Marks)

		******		·	
			Marks	СО	Blooms Level
		UNIT-I			
1.	a)	Summarize the different BJT configurations.	7M	1	2
	b)	Discuss how voltage divider bias is more advantageous than fixed bias.	7M	1	2
		OR			
2.	a)	Determine the stability factor of a fixed bias silicon transistor with the following specifications: $V_{CC} = 9V$, $R_C = 3$ K Ohms, $R_B = 8$ K Ohms, $R_$	7M	1	3
	b)	Write short notes on Thermal Resistance and Thermal Stability.	7M	1	6
	,	UNIT-II			
3.	a)	Write the necessary steps for gate bias circuit design and voltage divider bias			
	,	circuit design.	7M	2	6
	b)	What are the differences between Bipolar Junction Transistor & Field Effect			
	,	Transistor?	7M	2	1
		OR			
4.		Explain the construction, working principle and characteristics of enhancement			
		mode MOSFETS.	14M	2	2
		UNIT-III			
5.	a)	Draw and explain the amplifier equivalent circuit in detail	7M	3	3
	b)	Explain about Voltage gain, Current gain and Power gain of an amplifier when it			
		is drawn in equivalent circuit form	7M	3	2
		OR			
6.		Derive the expressions for input resistance, output resistance and voltage gain			
		of an emitter follower circuit.	14M	3	2
_	,	UNIT-IV	71.4		0
7.	a)	What is the importance of input impedance in amplifier circuit, Explain?	7M	4	2
	b)	What are the advantages of FET amplifier over BJT amplifier?	7M	4	2
_	,	OR			
8.	a)	Draw and explain the notations of AC Equivalent circuit for MOSFETs	7M	4	2
	b)	Briefly explain about Common Source MOSFET Amplifier.	7M	4	1
		UNIT-V			
9.	a)	Discuss the principle of operation of UJT.	7M	5	1
	b)	Write a note on LED.	7M	5	2
		OR			
10.	a)	In what respect is an LED different from an ordinary PN junction diode? State	A	_	0
	L. V	applications of LED.	7M	5	3
	b)	Explain the working principle of UJT with neat diagram. Mention its applications.	7M	5	4

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I B.Tech. II Semester Supplementary Examinations July/August 2022

Engineering Chemistry

(Common to EEE & ECE)

Max. Marks: 70 Time: 3 Hours

Answer any five full questions by choosing one question from each unit (5x14 = 70 Marks)

			Marks	СО	Blooms Level
		UNIT-I			
1.	a)	List out the different types of ion selective electrodes.	10M	CO1	L1
	b)	Define electrode potentials with examples.	4M	CO1	L1
		OR			
2.	a)	Differentiate an electrochemical cell and galvanic cell.	7M	CO1	L4
	b)	Apply electrochemical convention methods to represent the cell.	7M	CO1	L4
		LINUT II			
3.	a)	UNIT-II List out the Merits of fuel cell	8M	000	1.4
٥.	a) b)	Write short notes on i) electrode ii) electrolyte iii) salt bridge.	6M	CO2	L1
	D)	OR	Olvi	CO2	L1
4.		Discuss the construction and working principle of Zinc-air battery	14M	CO2	L3
••		Disouss the constitution and working principle of Zino all battery	I TIVI	002	LS
		UNIT-III			
5.	a)	Write short notes on the preparation of multi-crystalline and amorphous			
		Silicon.	8M	CO3	L1
	b)	List out the various applications of solar energy.	6M	CO3	L1
_		OR	4 45 4		
6.		Illustrate the doping mechanism of n and -p-type Silicon Semiconductors	14M	CO3	L4
		UNIT-IV			
7.	a)	Write the preparation, properties and uses of urea-formaldehyde resin.	10M	CO4	L1
	b)	What is step growth polymerization? Explain with examples.	4M	CO4	L1
		OR			
8.	a)	Discuss the various steps of free radical polymerization with examples	10M	CO4	L2
	b)	Explain the various types of stereospecific polymers with examples.	4M	CO4	L2
0	a)	UNIT-V	10M	005	1.4
9.	a) b)	List out various application of TEM What are rotaxanes and catenanes? Give examples.	4M	CO5	L1
	D)	OR	4111	CO5	L1
10.		Explain the function of cyclodextrin based switches,			
		i) in and out switching			
		ii) back and forth switching.	14M	CO5	L3
